NSN 5961-01-580-0779

Transistor - Page 1 of 1



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Ca70608-00 (19156), receiver-transmitter; an/trn-41

Mounting Facility Quantity:

2

Mounting Method:

Unthreaded hole

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage, dc and 4.0 emitter to base voltage, dc and 50.0 source supply voltage

Current Rating Per Characteristic:

2.50 amperes collector current, dc

Power Rating Per Characteristic:

25.0 watts pulse rf power

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Product Name:

Inavy: transistor, rf; cage 19156: rf transistor

Special Features:

Common base bipolar transistor; 25 watts, 50 volts, pulsed avionics 960 - 1215 mhz; storage temp: m65.0/p150.0 degrees c; case

outline: 55cx, style 1

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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